Midterm Exam # 2 April 15, 2004 Time Allowed: 80 minutes

Name:_____, _____ Last First

Student ID #:_____, Signature:_____

Student ID "._____, Signature._____

Discussion Section:

This is a closed-book exam, except for use of two 8.5 x 11 inch sheet of your notes. Show all your work to receive full or partial credit. Write your answers clearly in the spaces provided.

Problem #:	Points:
1	/10
2	/20
3	/20
Total	/50

1.

a) (5 points)

A silicon sample is uniformly doped with Boron to a concentration of $10^{16} atoms / cm^3$. Determine the resistivity of the sample at room temperature. Use electron mobility = $\mu_n = 1000 \text{ cm}^2/\text{v-s}$, hole mobility = $\mu_p = 400 \text{ cm}^2/\text{v-s}$, $Q = 1.6 \cdot 10^{-19} \text{ C}$ and $n_i = 10^{10}$ at room temperature.

b) (5 points)

The same sample is then to be counter doped to a depth of 5 μm with Arsenic atoms to create a resistor technology with resistance of 100 Ω/\Box . Determine the required Arsenic doping density.



a) (10 points)

The diode in Figure 2(a) is ideal. The waveform $V_s(t)$ is a balanced square wave with amplitude of 10 V and period 1 mS. Take L = 50 μ H and R = 1 Ω .

The circuit operates in a periodic steady state. Sketch and carefully dimension one period of the $i_L(t)$ waveform on the axes below. Make reasonable approximations.



b) (10 points)





In the circuit of Figure 2(b), switch S_1 is initially closed and switch S_2 is initially open and the circuit is in equilibrium. Switch S_1 is then opened and switch S_2 is closed for a sufficiently long time so that the circuit can be considered to be in equilibrium. How much energy is dissipated in the 1 $k\Omega$ resistor during the transient?

Hint: Think in terms of net charge and energy flow. Detailed transient analysis is **NOT** needed.





parameters listed in Figure 3.

a) (5 points)

Determine the required bias voltage V_G so that M1 is biased in saturation with $V_{DS} = 2$ V. Take $v_S = 0$

b) (10 points)

Draw the small signal model for this circuit. Compute the parameters of this small signal model.

c) (5 points)

Determeine the small signal gain
$$A_V = \frac{v_0}{v_S}$$
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